L Number	Hits	Search Text	DB	Time stamp
3	1423	silicon near1 precursor	USPAT;	2004/10/01 10:01
		_	US-PGPUB;	
			EPO; JPO	
4	188	(silicon near1 precursor) with (cvd	USPAT;	2004/10/01 10:03
		(chemical nearl vapor nearl deposition))	US-PGPUB;	
5	11	//ailian manul manauman) with /aud	EPO; JPO	2004/10/01 10 02
3	11	((silicon near1 precursor) with (cvd (chemical near1 vapor near1 deposition)))	USPAT; US-PGPUB;	2004/10/01 10:03
		and (low nearl k nearl dielectric)	EPO; JPO	
6	17	((silicon near1 precursor) with (cvd	USPAT;	2004/10/01 09:29
		(chemical near1 vapor near1 deposition)))	US-PGPUB;	
		and (low near1 k)	EPO; JPO	
7	17	((silicon nearl precursor) with (cvd	USPAT;	2004/10/01 09:36
		(chemical near1 vapor near1 deposition)))	US-PGPUB;	
		and (omcts octamethylcyclotetrasiloxane	EPO; JPO	
•	5	tmcts tetramethylcyclotetrasiloxane)	110024	2004/10/01 00 75
8	5	(((silicon near1 precursor) with (cvd (chemical near1 vapor near1 deposition)))	USPAT; US-PGPUB;	2004/10/01 09:36
		and (omcts octamethylcyclotetrasiloxane	EPO; JPO	
		tmcts tetramethylcyclotetrasiloxane)) and	1210, 310	
		(low nearl k)		
9	0	20040156987.URPN.	USPAT	2004/10/01 09:32
10	1	"20040101633"	USPAT;	2004/10/01 09:36
			US-PGPUB;	
, ,	_		EPO; JPO	0001/00/22 22
11	1	"20040101633" and (omcts	USPAT;	2004/10/01 10:04
		octamethylcyclotetrasiloxane tmcts tetramethylcyclotetrasiloxane)	US-PGPUB; EPO; JPO	
12	1	("20040101633" and (omcts	USPAT;	2004/10/01 09:37
	_	octamethylcyclotetrasiloxane tmcts	US-PGPUB;	2004/10/01 03.37
		tetramethylcyclotetrasiloxane)) and (low	EPO; JPO	
		near1 k)		
13	1	(("20040101633" and (omcts	USPAT;	2004/10/01 09:37
		octamethylcyclotetrasiloxane tmcts	US-PGPUB;	
		tetramethylcyclotetrasiloxane)) and (low near1 k)) and precursor	EPO; JPO	
14	1	((("20040101633" and (omcts	USPAT;	2004/10/01 09:48
	-	octamethylcyclotetrasiloxane tmcts	US-PGPUB;	2004/10/01 09.48
		tetramethylcyclotetrasiloxane)) and (low	EPO; JPO	
		near1 k)) and precursor) and (cvd		
		(chemical near1 vapor near1 deposition))		
15	1	(((("20040101633" and (omcts	USPAT;	2004/10/01 09:49
		octamethylcyclotetrasiloxane tmcts tetramethylcyclotetrasiloxane)) and (low	US-PGPUB;	
		nearl k)) and precursor) and (cvd	EPO; JPO	
		(chemical near1 vapor near1 deposition)))		
		and (cvd (chemical near1 vapor near1		
		deposition))		
16	1	(((("20040101633" and (omcts	USPAT;	2004/10/01 10:04
		octamethylcyclotetrasiloxane tmcts	US-PGPUB;	
		tetramethylcyclotetrasiloxane)) and (low	EPO; JPO	
		<pre>nearl k)) and precursor) and (cvd (chemical nearl vapor nearl deposition)))</pre>		
		and (cmp (chemical near) mechanical near)		
		polishing))		
17	0	(silicon near1 precursor) and	USPAT;	2004/10/01 10:00
		((((("20040101633" and (omcts	US-PGPUB;	
		octamethylcyclotetrasiloxane tmcts	EPO; JPO	
		tetramethylcyclotetrasiloxane)) and (low		
	j	near1 k)) and precursor) and (cvd		
		<pre>(chemical near1 vapor near1 deposition))) and (cmp (chemical near1 mechanical near1</pre>		
		polishing)))		
18	1	((((("20040101633" and (omcts	USPAT;	2004/10/01 10:01
		octamethylcyclotetrasiloxane tmcts	US-PGPUB;	
		tetramethylcyclotetrasiloxane)) and (low	EPO; JPO	
		near1 k)) and precursor) and (cvd		
		(chemical near1 vapor near1 deposition)))		,
		and (cmp (chemical near) mechanical near)		
LI		polishing))) and precursor	1	<u> </u>

10	040		1	1 2 2 2 1 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2
19	842		USPAT;	2004/10/01 10:03
	l	(chemical near1 vapor near1 deposition))	US-PGPUB;	
			EPO; JPO	
20	74	((silicon near1 precursor) and (cvd	USPAT;	2004/10/01 10:04
		(chemical near1 vapor near1 deposition)))	US-PGPUB;	
		and (low near1 dielectric)	EPO; JPO	
21	18	(((silicon near1 precursor) and (cvd	USPAT:	2004/10/01 10:04
		(chemical near1 vapor near1 deposition)))	US-PGPUB;	
		and (low near1 dielectric)) and (cmp	EPO; JPO	
		(chemical near1 mechanical near1		
		polishing))		
22	8	((((silicon near1 precursor) and (cvd	USPAT:	2004/10/01 10:05
		(chemical near1 vapor near1 deposition)))	US-PGPUB;	,,
		and (low near1 dielectric)) and (cmp	EPO: JPO	
		(chemical near1 mechanical near1	EFO, OFO	
		polishing))) and (omcts		
ļ		octamethylcyclotetrasiloxane tmcts		
	ì			
		tetramethylcyclotetrasiloxane)	l	
23	1	6287990.pn.	USPAT;	2004/10/01 10:55
			US-PGPUB;	
			EPO; JPO	
24	1	6287990.pn. and (low near1 dielectric)	USPAT;	2004/10/01 10:55
			US-PGPUB;	
			EPO; JPO	